TECHNICAL DATA DATA SHEET 574, REV. A

# HERMETIC POWER SCHOTTKY RECTIFIER Very Low Forward Voltage Drop

**DESCRIPTION:** 45 VOLT, 30 AMP, POWER SCHOTTKY RECTIFIER IN A HERMETIC TO-254 PACKAGE.

## **MAXIMUM RATINGS**

ALL RATINGS ARE @  $T_C$  = 25 °C UNLESS OTHERWISE SPECIFIED.

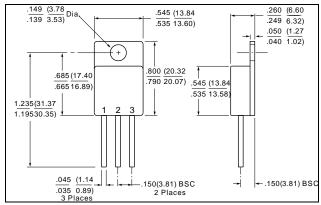
RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	45	Volts
MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ T <sub>C</sub> =100 <sup>O</sup> C)	Io	35	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT	I <sub>FSM</sub>	150	Amps
(t = 8.3ms, Sine)			
MAXIMUM JUNCTION CAPACITANCE (V <sub>r</sub> =5V)	C <sub>T</sub>	2400	pF
MAXIMUM THERMAL RESISTANCE	$R\theta_{JC}$	1.15	°C/W
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE	Top/Tstg	-65 to + 175	°C

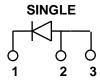
### **ELECTRICAL CHARACTERISTICS**

CHARACTERISTIC		SYMBOL	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP, Pulsed (				
-	T <sub>J</sub> = 25 °C	$V_{f}$	0.71	Volts
-	T <sub>J</sub> = 125 °C	- 1	0.62	
MAXIMUM REVERSE CURRENT (I <sub>r</sub> @ 45V PIV)				
-	T <sub>J</sub> = 25 °C	$I_r$	4.5	mA
-	T <sub>.1</sub> = 125 °C		210	

## DATA SHEET 574, REV. A

#### **MECHANICAL DIMENSIONS: In Inches / mm**



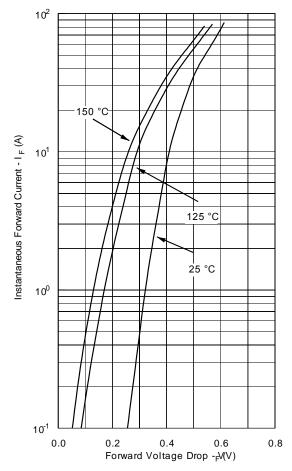


**TO-254** 

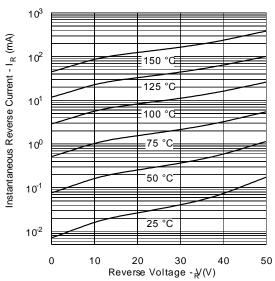
#### **PINOUT TABLE**

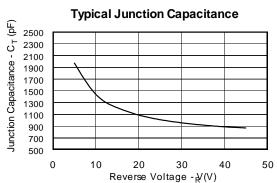
TYPE	PIN 1	PIN 2	PIN 3	
SINGLE RECTIFIER	CATHODE	ANODE	ANODE	

## **Typical Forward Characteristics**



## **Typical Reverse Characteristics**





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**DATA SHEET 574, REV. A** 

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